## ESMT/EMP

# Fast Ultra High-PSRR, Low-Noise, 300mA CMOS Linear Regulator

#### **General Description**

The EMP8737 features ultra-high power supply rejection ratio, low output voltage noise, low dropout voltage, low quiescent current and fast transient response. It guarantees delivery of 300mA output current for V<sub>IN</sub>=2.2V ~ 5.5V and supports preset output voltages ranging from 0.8V to 4.5V with 0.05V increment. It also guarantees delivery of 100mA output current for V<sub>IN</sub> range lower from 1.75V ~ 2.1V.

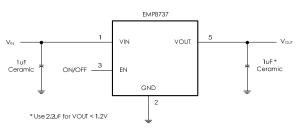
Based on its low quiescent current consumption and its less than  $1\mu$ A shutdown mode of logical operation, the EMP8737 is ideal for battery-powered applications. The high power supply rejection ratio of the EMP8737 holds well for low input voltages typically encountered in battery-operated systems. The regulator is stable with small ceramic capacitive loads ( $1\mu$ F typical). The EMP8737 is Available in miniature SOT-23-5 package.

#### **Features**

- 2.2V to 5.5V input range for Iout 300mA operation
- 1.75V to 2.1V input range for IOUT 100mA operation
- 62dB typical PSRR at 1kHz
- 110µV RMS output voltage noise (10Hz to 100kHz)
- 290mV typical dropout at 300mA
- 57µA typical quiescent current
- Less than 1µA typical shutdown mode
- Fast line and load transient response
- Auto-discharge during chip disable
- 80µs typical turn-on time
- Stable with small ceramic output capacitors
- Over temperature and over current protection
- ±2% output voltage tolerance

#### **Applications**

- Wireless handsets
- PCMCIA cards
- DSP core power
- Hand-held instruments
- Battery-powered systems
- Portable information appliances

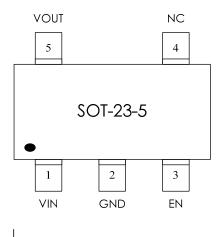


\*Use 2.2 $\mu$ F for V<sub>OUT</sub> < 1.2V

#### **Typical Application**

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#### CONNECTION DIAGRAM SOT-23-5(TOP View)



## **ORDER INFORMATION**

EMP8737-XXVF05GRR			
XX	Output Voltage		
VF05	SOT-23-5 Package		
NRR	RoHS & Halogen free		
	Commercial Grade Temperature		
	Rating: -40 to 85°C		
	Package in Tape & Reel		

## **Pin Functions**

Name	SOT-23-5	Function		
VIN		Supply Voltage Input. Require a minimum input capacitor of close to $1\mu$ F to		
VIN	1	ensure stability and sufficient decoupling from the ground pin.		
GND	2	Ground Pin.		
		Enable Input. Enable the regulator by pulling the EN pin High. To keep the		
EN	3	regulator on during normal operation, connect the EN pin to VIN. The EN pin		
		must not exceed VIN + 0.5V under all operating conditions.		
NC	4	No Connection		
VOUT	5	Output Voltage Feedback.		

### Order, Mark & Packing Information

Marking	Vout	Product ID	Packing
5 873 Tracking PINI DOT	1.2	EMP8737-12VF05GRR	3K units Tape & Reel

#### Absolute Maximum Ratings (Notes 1, 2)

VIN, VOUT, VEN	-0.3V to 6.5V	Thermal Resistance ( $\theta_{JA}$ )	
Storage Temperature Range	-65°C to160°C	SOT-23-5	250°C/W
Junction Temperature (TJ)	150°C		
Lead Temperature (10 sec.)	260°C	<b>Operating Ratings</b> (Note 1, 2)	
ESD Rating		Temperature Range	-40°C to 85°C
Human Body Model	2kV	Supply Voltage	2.2V to 5.5V
MM	200V		

#### **Electrical Characteristics**

Unless otherwise specified, all limits guaranteed for  $V_{IN} = V_{OUT} + 1V$  (Note 3),  $V_{EN} = V_{IN}$ ,  $C_{IN} = C_{OUT} = 2.2\mu$ F,  $T_A = 25^{\circ}$ C. Boldface & underline limits apply for the operating temperature extremes: -40°C and 85°C.

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
VIN	Input Voltage	I <sub>OUT</sub> = 300mA (max.)	<u>2.2</u>		<u>5.5</u>	V	
Vout	Output Voltage		<u>0.8</u>		<u>4.5</u>	V	
$\Delta V_{OTL}$	Output Voltage Tolerance	louτ = 10mA (Note 3)	-2		+2	% of	
-			<u>-3</u>		<u>+3</u>	Vout (NOM)	
IOUT	Maximum Output Current	V <sub>IN</sub> = 2.2V ~ 5.5V	<u>300</u>			mA	
Ilimit	Output Current Limit		<u>300</u>	450		mA	
		I <sub>OUT</sub> = 0mA		57			
	Sumply Current	I <sub>OUT</sub> = 50mA		63			
lq	Supply Current	I <sub>OUT</sub> = 150mA		88		μA	
		I <sub>OUT</sub> = 300mA		130			
	Shutdown Supply Current	V <sub>OUT</sub> = 0V, EN = GND		0.001	1		
	Dropout Voltage (Note4)	I <sub>OUT</sub> = 100mA		90			
$V_{DO}$		I <sub>OUT</sub> = 300mA		290		mV	
$\Delta V_{OUT}$	Line Regulation	$I_{OUT} = 1 \text{ mA}, (V_{OUT} + 1 \text{ V}) \le V_{IN} \le$ 5.5V (Note 3)	-0.1	0.01	0.1	%/V	
	Load Regulation	$1 \text{mA} \le I_{\text{OUT}} \le 300 \text{mA}$		0.0008		%/mA	
en	Output Voltage Noise	$V_{OUT}$ =2.5V, $I_{OUT}$ = 10mA, 10Hz $\leq$ f $\leq$ 100kHz		110		μV <sub>RMS</sub>	
	Thermal Shutdown			165			
T <sub>SD</sub>	Temperature			100		°C	
.30	Thermal Shutdown			35		Ũ	
	Hysteresis			00			
V <sub>EN</sub>	EN Input Threshold	$V_{IH}$ , $(V_{OUT} + 1V) \le V_{IN} \le 5.5V$ (Note 3)	<u>1.2</u>				
		$V_{IL}$ ( $V_{OUT}$ + 1V) $\leq$ $V_{IN} \leq$ 5.5V (Note 3)			<u>0.4</u>	- V	
I <sub>EN</sub>	EN Input Bias Current	$EN = GND \text{ or } V_{IN}$		0.1	100	nA	
Ton	Turn-On Time	Vout at 95% of Final Value		80		μs	
TOFF	Turn-Off Time	Iour=0mA (Note 5)		2.4		ms	

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#### **Electrical Characteristics (cont.)**

Unless otherwise specified, all limits guaranteed for  $V_{EN}=V_{IN}$ ,  $C_{IN}=C_{OUT}=2.2\mu$ F,  $T_A=25^{\circ}$ C.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	Input Voltage	I <sub>out</sub> = 100mA (max.)	1.75		2.1	V
$\Delta V_{\text{OTL}}$	Output Voltage Tolerance	$1 \text{mA} \le I_{\text{OUT}} \le 100 \text{mA},$ $1.75 \text{V} \le \text{V}_{\text{IN}} \le 2.1 \text{V}$	-2		+2	% of V <sub>OUT (NOM)</sub>
Гоит	Maximum Output Current	V <sub>IN</sub> = 1.75V ~ 2.1V	50		100	mA

Note 1: Absolute Maximum ratings indicate limits beyond which damage may occur. Electrical specifications do not apply when operating the device outside of its rated operating conditions.

Note 2: All voltages are with respect to the potential at the ground pin.

Note 3: Condition does not apply to input voltages below 2.2V since this is the minimum input operating voltage.

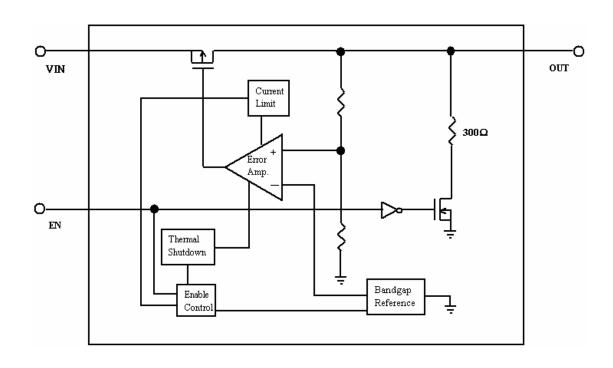
Note 4: Dropout voltage is measured by reducing  $V_{IN}$  until  $V_{OUT}$  drops 100mV from its nominal value at  $V_{IN}$  - $V_{OUT}$  = 1V. Dropout voltage does not apply to the regulator versions with  $V_{OUT}$  less than 2.2V.

Note 5: Turn-off time is time measured between the enable input just decreasing below V<sub>IL</sub> and the output voltage just decreasing to 10% of its nominal value.

Note 6: Maximum Power dissipation for the device is calculated using the following equations:

$$P_{D} = \frac{T_{J}(MAX) - T_{A}}{\theta_{JA}}$$

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance. E.g. for the SOT-23-5 package  $\theta_{JA} = 250^{\circ}$ C/W,  $T_{J(MAX)} = 150^{\circ}$ C and using  $T_A = 25^{\circ}$ C, the maximum power dissipation is found to be 500mW. The derating factor  $(-1/\theta_{JA}) = -4$ mW/°C, thus below 25°C the power dissipation figure can be increased by 4mW per degree, and similarity decreased by this factor for temperatures above 25°C.

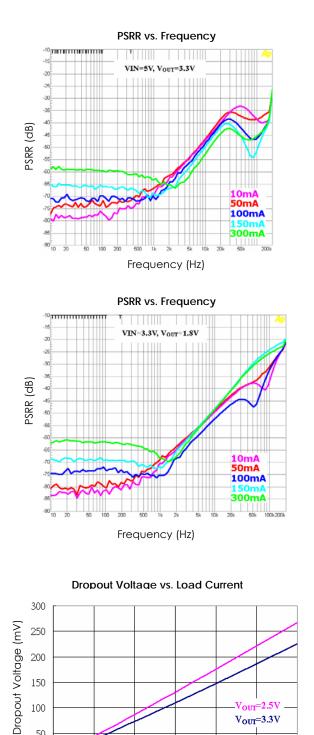


#### **Functional Block Diagram**



### **Typical Performance Characteristics**

Unless otherwise specified, VIN =  $V_{OUT (NOM)}$  + 1V,  $V_{EN}$ = $V_{IN}$ ,  $C_{IN}$  =  $C_{OUT}$  = 2.2µF,  $T_A$  = 25°C.



100

50

0

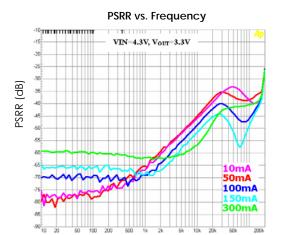
0

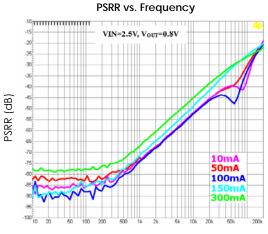
50

100

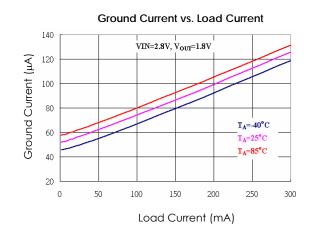
150

Load Current (mA)





Frequency (Hz)





200

Vout=3.3V

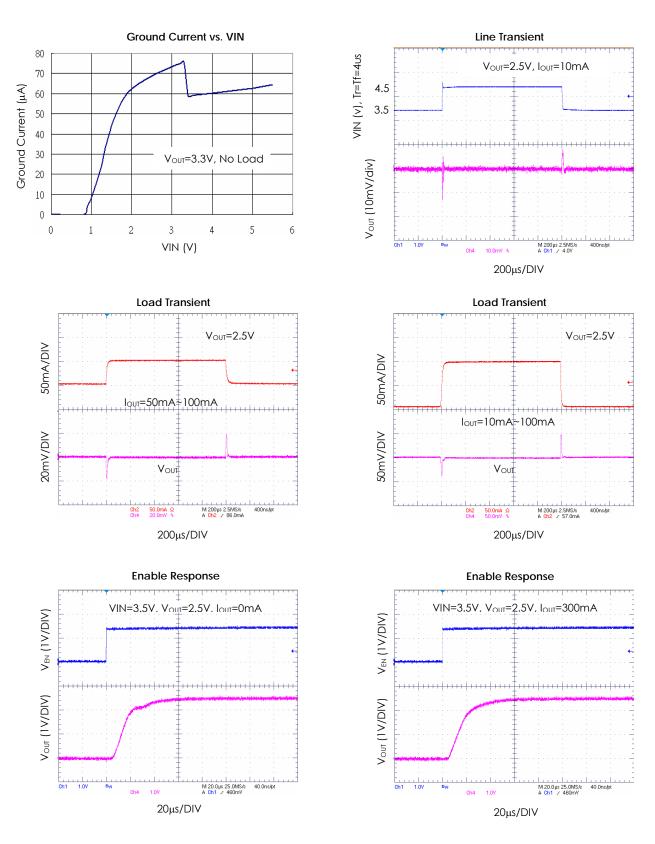
250

300

## ESMT/EMP

### **Typical Performance Characteristics**

Unless otherwise specified, VIN = V<sub>OUT (NOM)</sub> + 1V, V<sub>EN</sub>=V<sub>IN</sub>, C<sub>IN</sub> = C<sub>OUT</sub> = 2.2µF, T<sub>A</sub> = 25°C. (Continued)



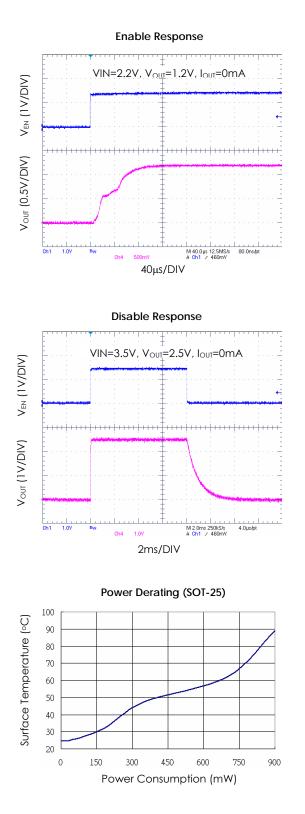
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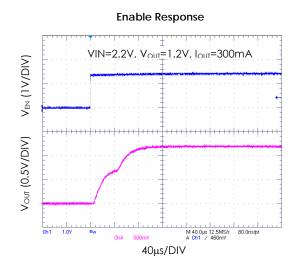
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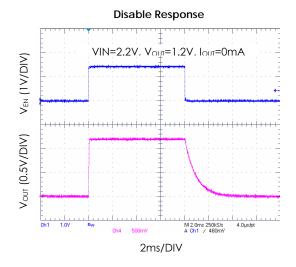


## Typical Performance Characteristics

Unless otherwise specified, VIN = V<sub>OUT (NOM)</sub> + 1V, V<sub>EN</sub>=V<sub>IN</sub>, C<sub>IN</sub> = C<sub>OUT</sub> = 2.2µF, T<sub>A</sub> = 25°C. (Continued)

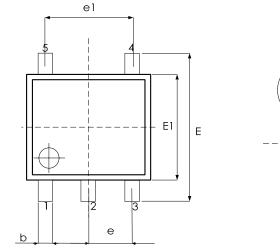


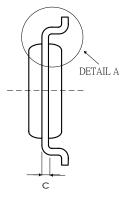


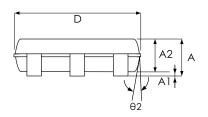


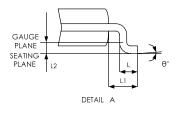


SOT-23-5









SYMBPLS	MIN.	NOM.	MAX.
А	1.05	1.20	1.35
A1	0.05	0.10	0.15
A2	1.00	1.10	1.20
b	0.30		0.50
С	0.08	_	0.20
D	2.80	2.90	3.00
E	2.60	2.80	3.00
E1	1.50	1.60	1.70
е	0.95 BSC		
el	1.90 BSC		
L	0.30	0.45	0.55
L1	0.60 REF		
L2	0.25 REF		
θ°	0	5	10
θ2°	6	8	10
			UNIT: MM



## **Revision History**

Revision	Date	Description
1.0	2011.05.28	Original version
1.1	2011.05.28	EN pin must not exceed VIN + 0.5V under all operating conditions
1.2	2011.07.04	Modify Output Voltage Tolerance



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